

Lasers

lecture 11

Czesław Radzewicz

solid state lasers (excluding semiconductor lasers)

matrix + dopant

isolators=crystals + glass + ceramics

transient metals
rare earth metals

Matrix:

oxides:

sapphire (Al_2O_3)

alexandrite (BeAl_2O_4)

YAG – aluminium yttrium garnet ($\text{Y}_3\text{Al}_5\text{O}_{12}$)

.....

fluorides:

LISAF (LiSrAlF_6)

YLF (YLiF_4)

.....

tungstate

$\text{KY}(\text{WO}_4)_2$

$\text{KGd}(\text{WO}_4)_2$

.....

Important parameters:

- bandgap
- thermal conductivity
- thermal lensing $\frac{dn}{dT}$
- mechanical properties
- FOM, $\text{FOM} = \frac{\alpha_p}{\alpha_l}$

dopants

- transient metals
- lanthanides

Group → ↓ Period	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
1	1 H																	2 He
2	3 Li	4 Be											5 B	6 C	7 N	8 O	9 F	10 Ne
3	11 Na	12 Mg											13 Al	14 Si	15 P	16 S	17 Cl	18 Ar
4	19 K	20 Ca	21 Sc	22 Ti	23 V	24 Cr	25 Mn	26 Fe	27 Co	28 Ni	29 Cu	30 Zn	31 Ga	32 Ge	33 As	34 Se	35 Br	36 Kr
5	37 Rb	38 Sr	39 Y	40 Zr	41 Nb	42 Mo	43 Tc	44 Ru	45 Rh	46 Pd	47 Ag	48 Cd	49 In	50 Sn	51 Sb	52 Te	53 I	54 Xe
6	55 Cs	56 Ba		72 Hf	73 Ta	74 W	75 Re	76 Os	77 Ir	78 Pt	79 Au	80 Hg	81 Tl	82 Pb	83 Bi	84 Po	85 At	86 Rn
7	87 Fr	88 Ra		104 Rf	105 Db	106 Sg	107 Bh	108 Hs	109 Mt	110 Ds	111 Rg	112 Cn	113 Uut	114 Fl	115 Uup	116 Lv	117 Uus	118 Uuo
Lanthanides				57 La	58 Ce	59 Pr	60 Nd	61 Pm	62 Sm	63 Eu	64 Gd	65 Tb	66 Dy	67 Ho	68 Er	69 Tm	70 Yb	71 Lu
Actinides				89 Ac	90 Th	91 Pa	92 U	93 Np	94 Pu	95 Am	96 Cm	97 Bk	98 Cf	99 Es	100 Fm	101 Md	102 No	103 Lr

dopants

Transient metals: atoms with the *d* shell partially empty

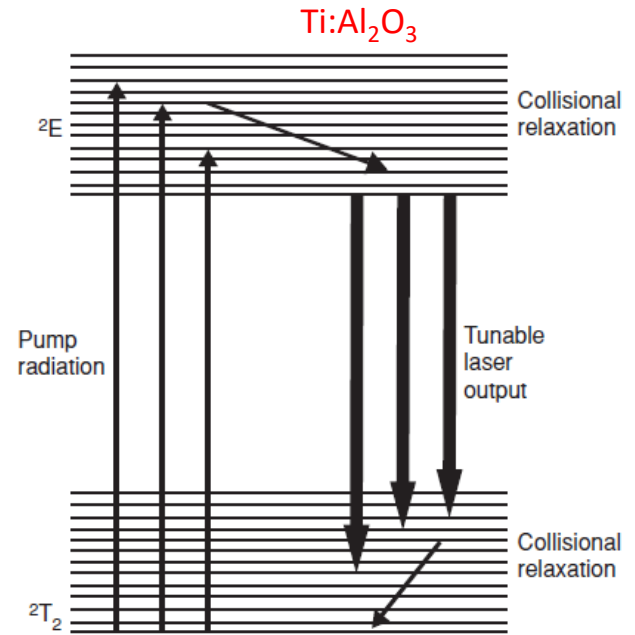
example: $Ti:Al_2O_3$

Electronic configuration of Ti: $1s^2 2s^2 2p^6 3s^2 3p^6 3d^2 4s^2 = Ar + 3d^2 4s^2$

In sapphire crystal the titanium atoms shed 3 electrons to become Ti^{3+} with electronic configuration $Ar + 3d^1$

Optical transitions – excitations of the 3*d* electron

The 3*d* electron occupies an external shell and thus its energy levels are sensitive to external perturbations. In effect, the transitions frequencies depend on the crystal matrix and strong coupling with phonons is observed



Lanthanides: atoms with the *f* shell partially empty

example : $Nd:YAG$

Electronic configuration of Nd atom : $1s^2 2s^2 2p^6 3s^2 3p^6 3d^{10} 4s^2 4p^6 4d^{10} 4f^4 5s^2 5p^6 6s^2 = Xe + 4f^4 5s^2 5p^6 6s^2$

Nd^{3+} ion has electronic configuration: $Xe + 4f^3 5s^2 5p^5$; optical transitions correspond to excitations of the *f* electron. It occupies 4*f* shell which is well shielded by 5*s*, 5*p* and 6*s* outer electrons.

Frequencies of optical transitions are not very sensitive to the matrix.

Nd:YAG $\lambda_l = 1,064 \mu m$

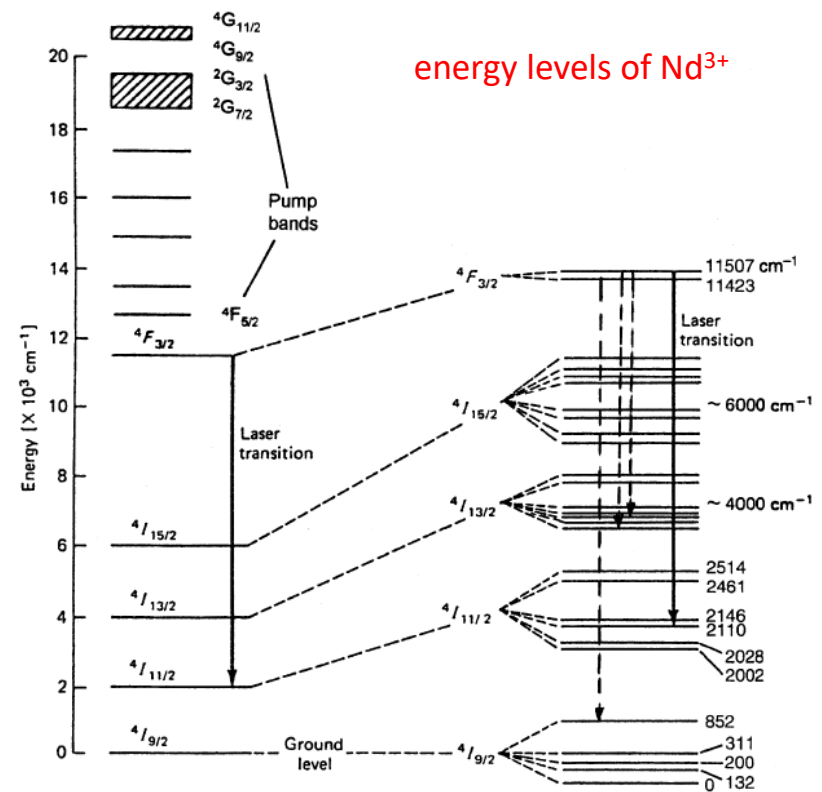
Nd:YLF $\lambda_l = 1,047 \mu m$

neodymium doped materials

$Nd:YAG - Y_3Al_5O_{12}:Nd^{3+}$

$Nd:YLF - YLiF_4:Nd^{3+}$

....



	YAG	YLF	glass
thermal conductivity, W/(m·K)	13	6	0.8
dn/dT [1/K]	$7 \cdot 10^{-6}$	$4.3 \cdot 10^{-6}$ $2 \cdot 10^{-6}$	$2 \cdot 10^{-6}$
τ [μs]	230	480	800
λ_l [μm]	1.064	1.047	1.059
σ [cm^2]	$1.8 \cdot 10^{-19}$	$2.4 \cdot 10^{-19}$	
$\Delta\nu$ [cm^{-1}]	≈ 6	≈ 6	≈ 300

Nd:YAG

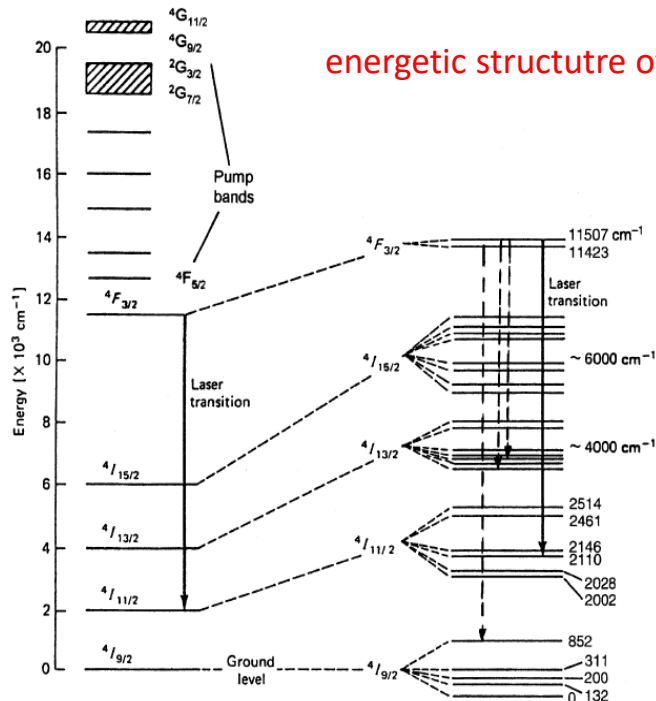


Table 2.2. Physical and optical properties of Nd:YAG

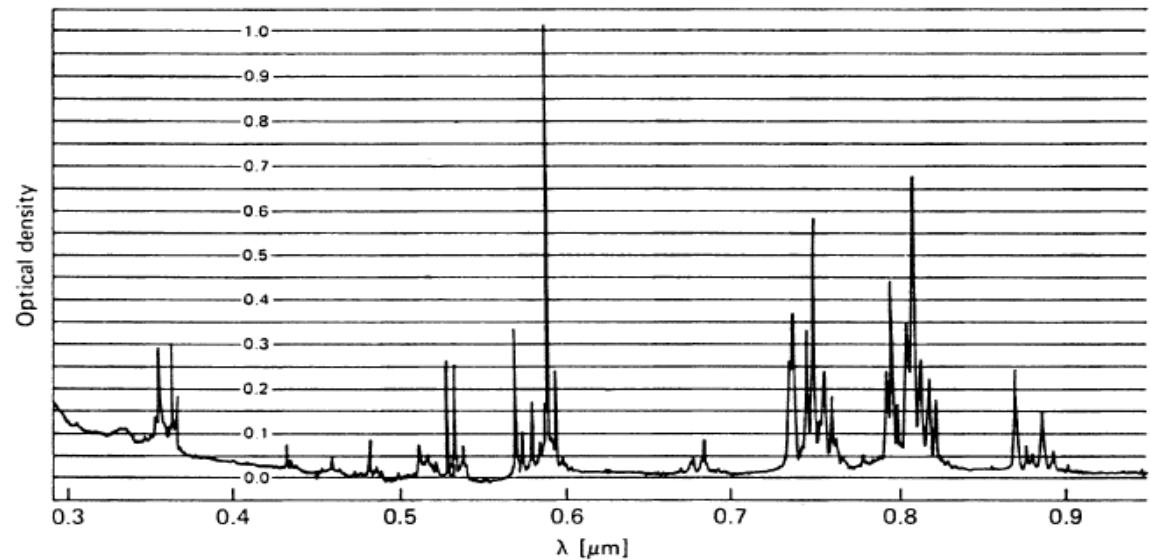
Chemical formula	Nd:Y ₃ Al ₅ O ₁₂
Weight % Nd	0.725
Atomic % Nd	1.0
Nd atoms/cm ³	1.38×10^{20}
Melting point	1970°C
Knoop hardness (kg/mm ²)	1320
Density	4.56 g/cm ³
Tensile strength	200 MPa
Modulus of elasticity	310 Gpa
Poisson ratio	0.30
Thermal expansion coefficient	
[100] orientation	$8.2 \times 10^{-6}/^{\circ}\text{C}$,
[110] orientation	$7.7 \times 10^{-6}/^{\circ}\text{C}$,
[111] orientation	$7.8 \times 10^{-6}/^{\circ}\text{C}$,
Linewidth	120 GHz
Stimulated emission cross section	
$R_2 - Y_3$	$\sigma = 6.5 \times 10^{-19} \text{ cm}^2$
$4F_{3/2} - 4I_{11/2}$	$\sigma = 2.8 \times 10^{-19} \text{ cm}^2$
Fluorescence lifetime	230 μs
Photon energy at 1.06 μm	$h\nu = 1.86 \times 10^{-19} \text{ J}$
Index of refraction	1.82 (at 1.0 μm)

Nd:YAG

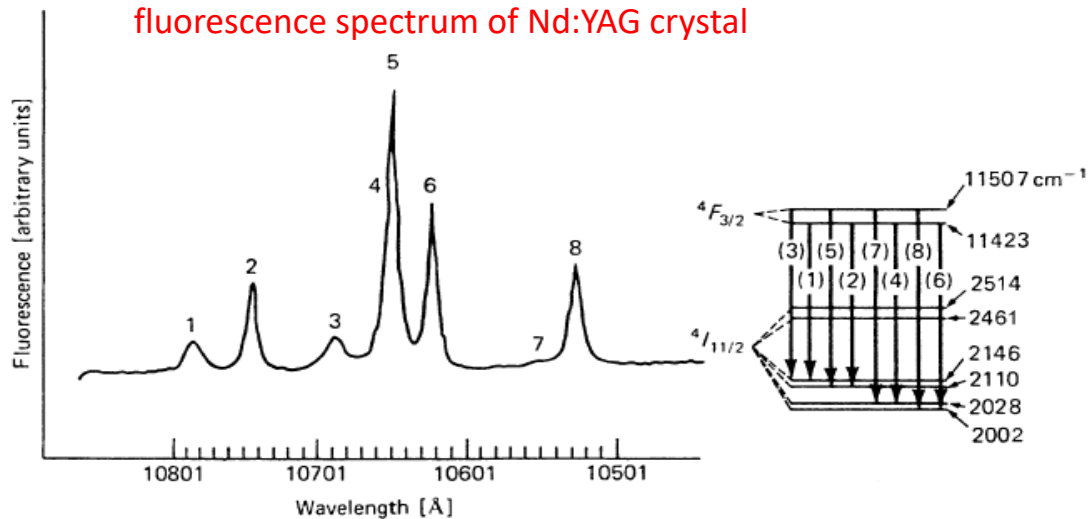
Laser crystals are pumped by:

- another laser
- flash lamp
- sunlight
- ????

absorption spectrum of Nd:YAG crystal



fluorescence spectrum of Nd:YAG crystal



alexandrite

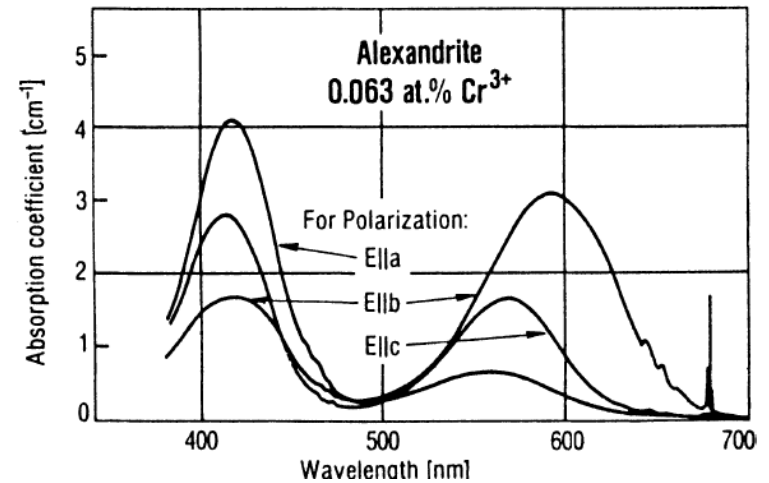
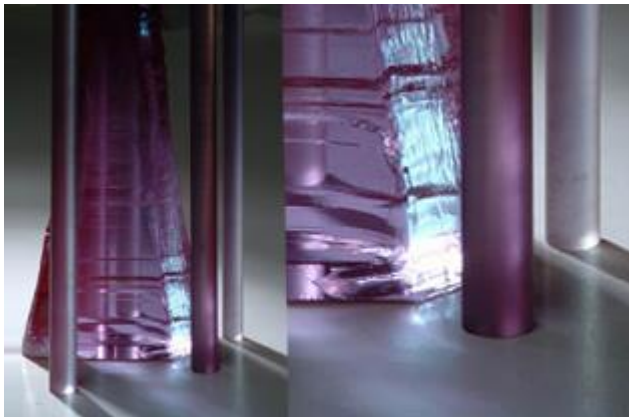
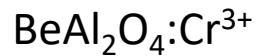
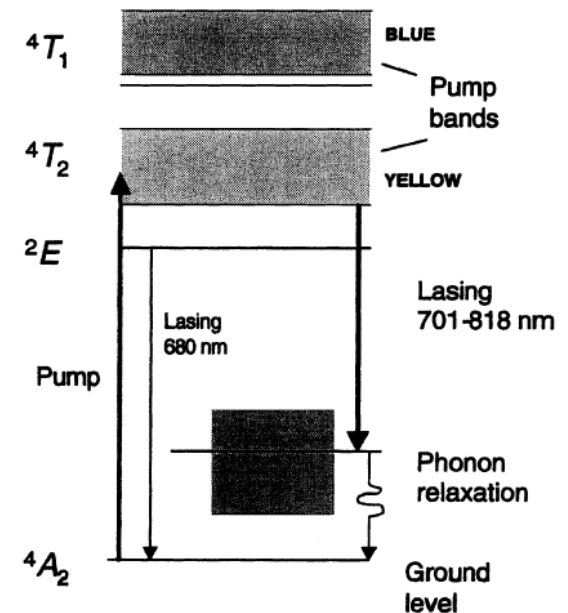


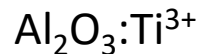
Table 2.9. Material parameters of alexandrite

Laser wavelength (nm)	700–818
Stimulated emission cross section (cm ²)	1.0×10^{-20}
Spontaneous lifetime (μs)	260 ($T = 298$ K)
Doping density (at.%)	0.05–0.3
Fluorescent linewidth (nm)	100
Gain coefficient for 1 J/cm ³ stored energy (cm ⁻¹)	0.038–0.19
Index of refraction (750 nm)	$E b$ 1.7421
Thermal expansion	b 6.1×10^{-6} /K
Thermal conductivity (W/cm K):	0.23
Melting point (°C)	1870
Hardness (kg/mm ²)	2000

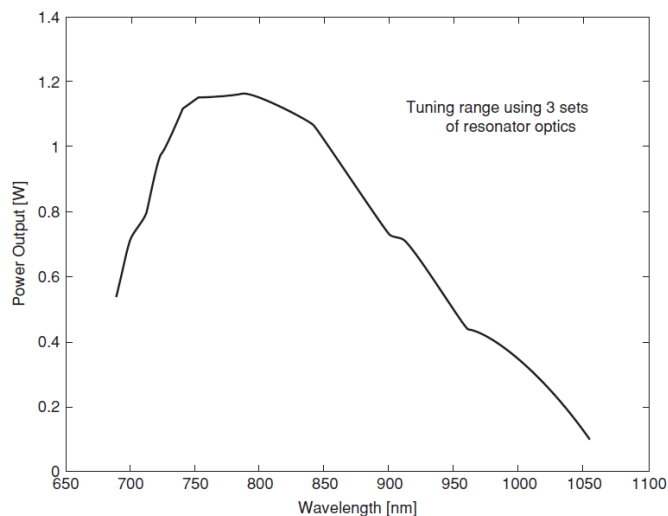
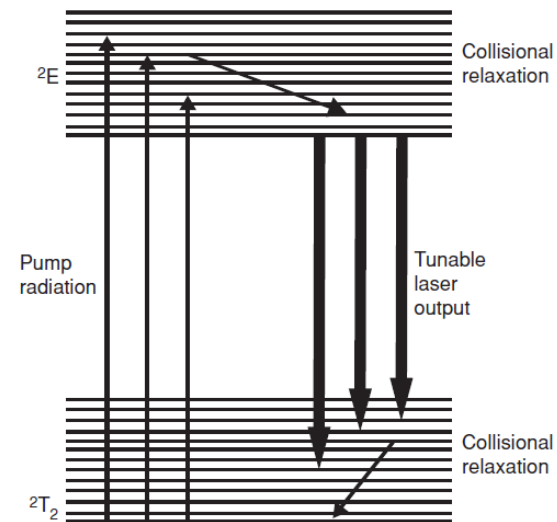


saturation fluence 40J/cm² !

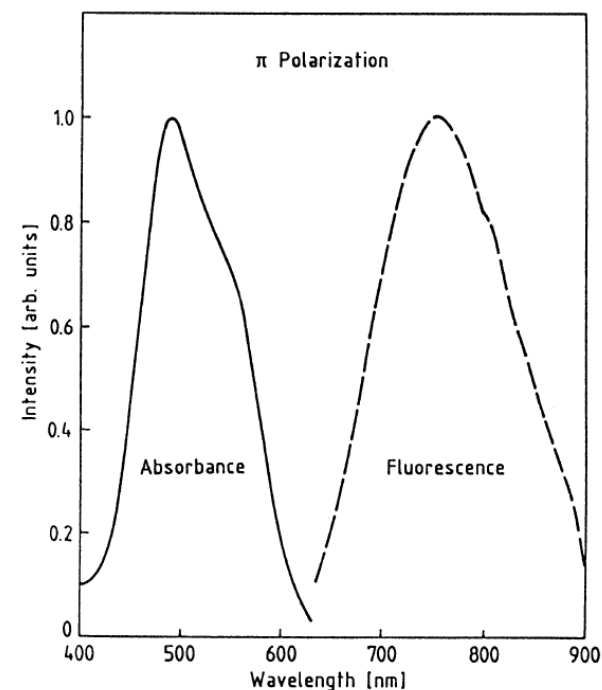
Ti:Sapphire



Index of refraction	1.76
Fluorescent lifetime	3.2 μs
Fluorescent linewidth (FWHM)	230 nm
Peak emission wavelength	780 nm
Peak stimulated emission cross section	
parallel to <i>c</i> -axis	$\sigma_{\parallel} \sim 4.1 \times 10^{-19} \text{ cm}^2$
perpendicular to <i>c</i> -axis	$\sigma_{\perp} \sim 2.0 \times 10^{-19} \text{ cm}^2$
Stimulated emission cross section	
at 0.795 μm	$\sigma_{\parallel} = 2.8 \times 10^{-19} \text{ cm}^2$
Quantum efficiency of	
converting a 0.53 μm photon	
into an inverted site	$n_Q \approx 1$
Saturation fluence at 0.795 μm	$E_s = 0.9 \text{ J/cm}^2$

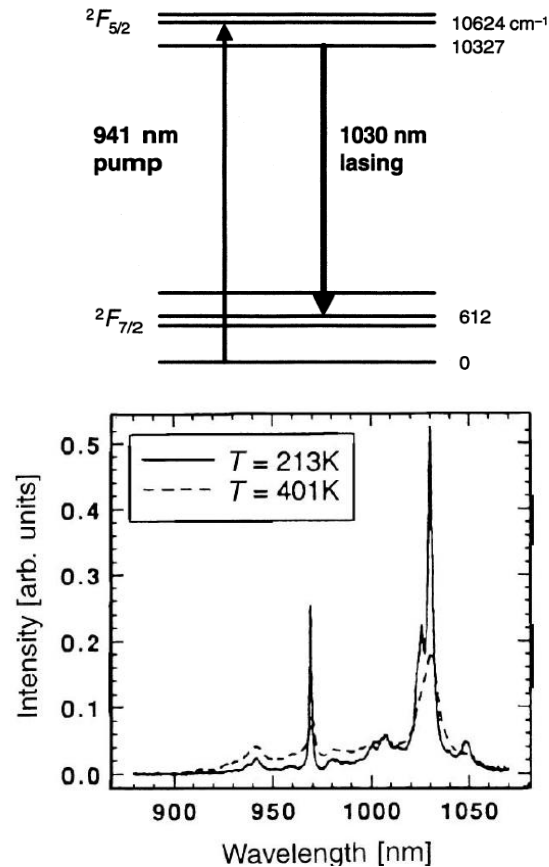


tuning range 690-1060 nm !



ytterbium doped laser materials

np. $\text{Yb}^{3+}:\text{YAG}$

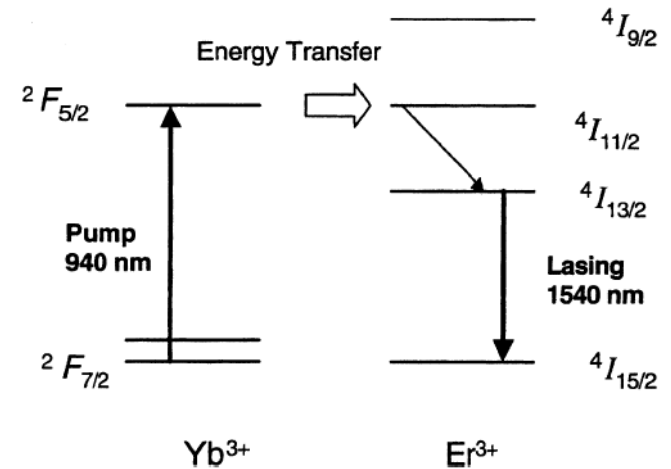


Laser wavelength	1030 nm
Radiative lifetime at room temperature	951 μs
Peak emission cross section	$2.1 \times 10^{-20} \text{ cm}^2$
Peak absorption wavelength	941 nm
Pump bandwidth at 941 nm	18 nm
Doping density (1% at.)	$1.38 \times 10^{20} \text{ cm}^{-3}$

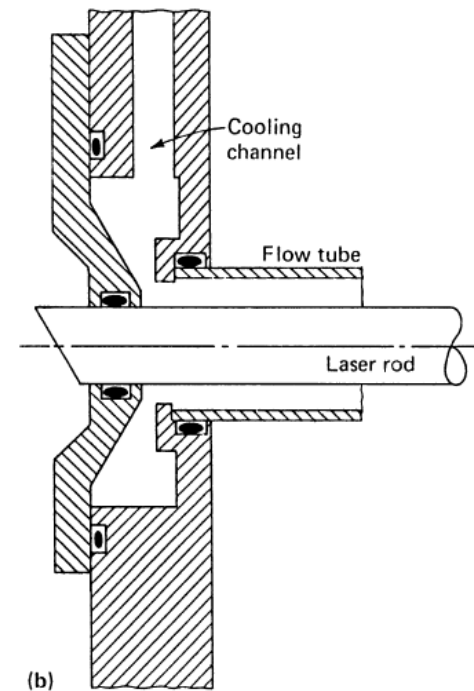
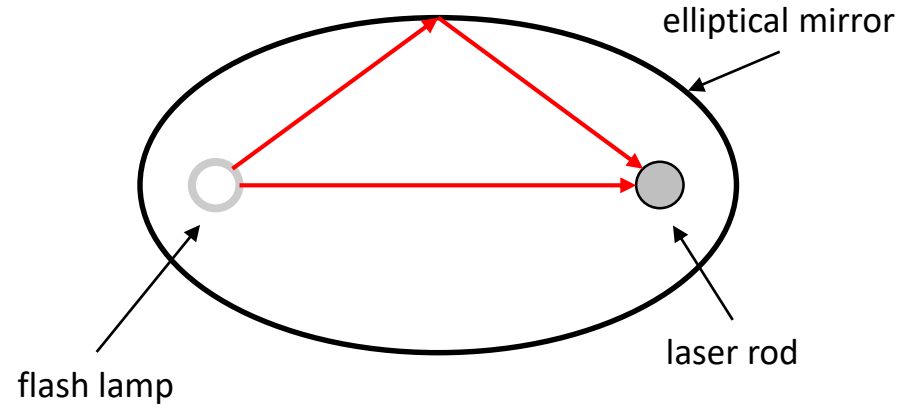
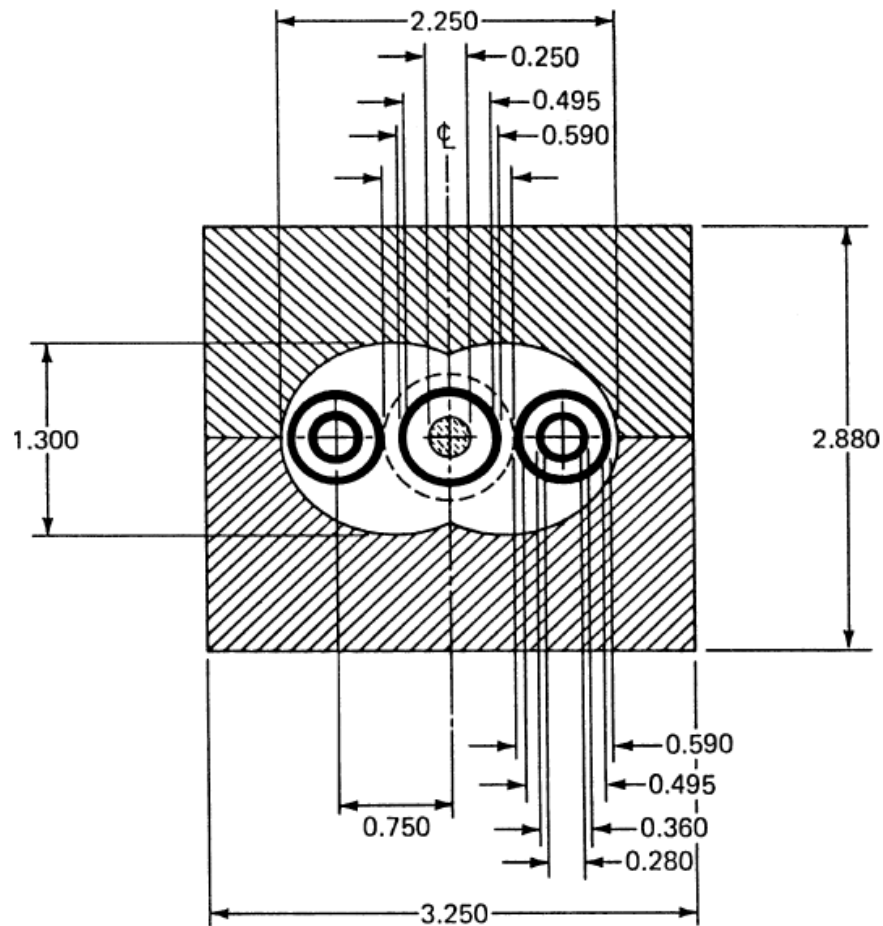
very small Stokes shift

erbium doped laser materials

EDA (Erbium Doped Amplifier)
fiber oscillators and amplifiers



Nd:YAG – flash lamp pumping



Nd:YAG – flash lamp pumping, 2

Let's normalize Nd:YAG absorption spectrum and the flash lamp emission spectrum:

$$\int \sigma_a(\lambda) d\lambda = 1, \int \sigma_e(\lambda) d\lambda = 1$$

Then the overlap integral

$$\eta_p = \int \sigma_e(\lambda) \sigma_a(\lambda) d\lambda \leq 1$$

Is a good measure of how well the lamp's spectrum matches the absorption spectrum.

In the case of Nd:YAG crystal and a krypton lamp (the best available) we have

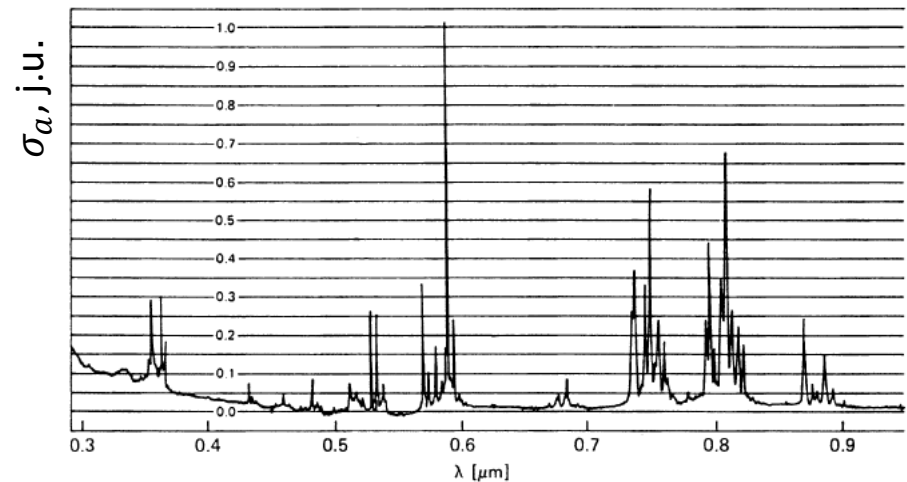
$$\eta_p \ll 1$$

In addition the short wavelength part of the spectrum absorber by the crystal heats it up.

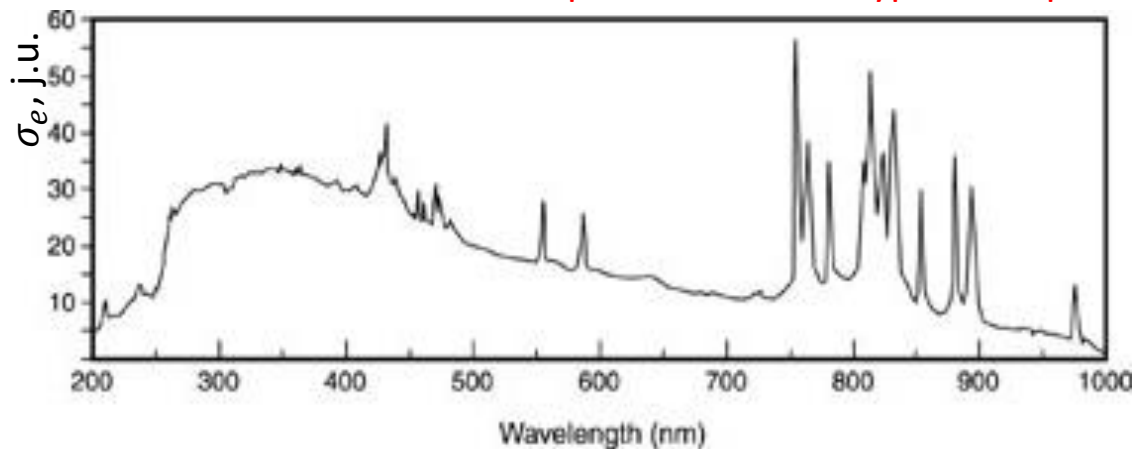
Table 6.5. Energy transfer in a cw krypton arc lamp, pumped Nd:YAG laser

Heat dissipation of lamps	55%
Heat dissipation of pump reflectors	30%
Power absorbed by coolant and flow tubes	7%
Heat dissipation by rod	5%
Laser output	2%
Fluorescence output	0.4%
Optical losses	0.6%
Power absorbed by laser rod	8%
Electrical input to lamps	100%

Nd:YAG crystal absorption spectrum

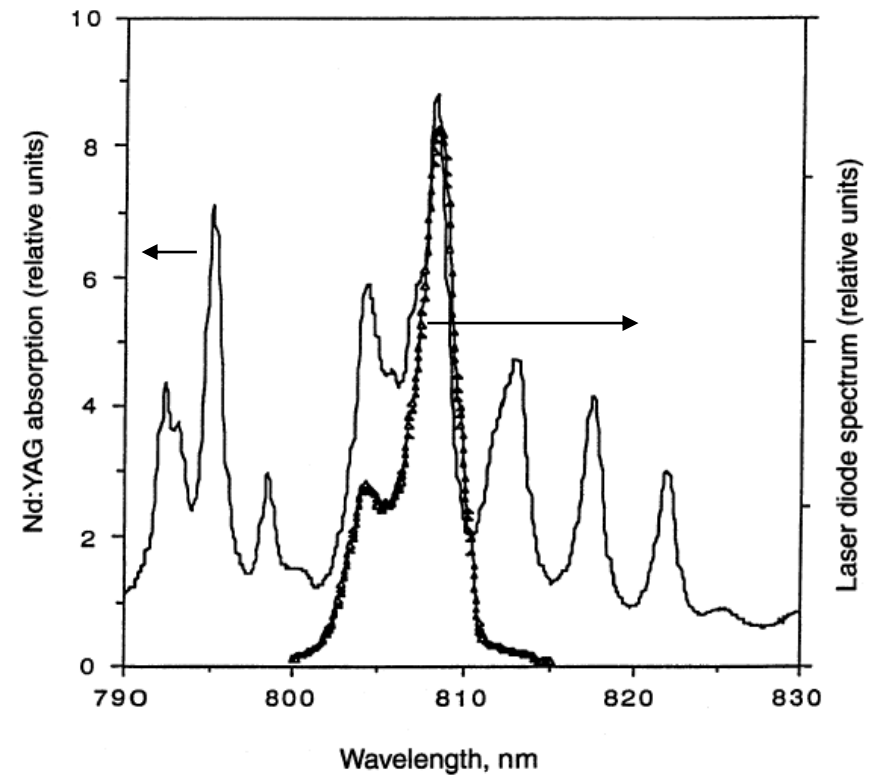


emission spectrum of the krypton lamp



Nd:YAG – diode pumping

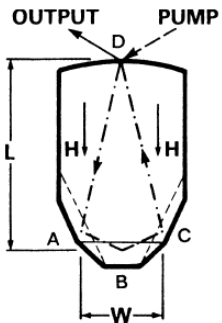
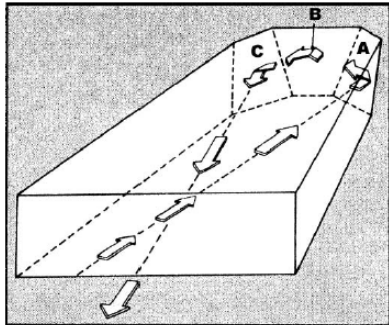
The absorption spectrum of Nd:YAG is typical for most laser crystals – it consists of many narrow peaks with little absorption in between. It is a much better strategy to use a narrowband source with the wavelength matched to one of the peaks.



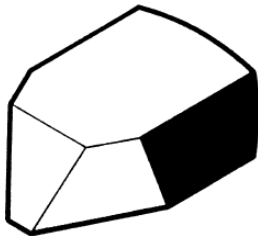
gain medium	λ_p [nm]	diode laser
Nd:YAG	808	GaAlAs
Yb:YAG	941	InGaAs
Nd:YVO ₄	809	GaAlAs
Nd:YLF	798	GaAlAs
Cr:LiSAF	670	AlGaInP (low power!)
Yb:KYW	975	InGaAs

Nd:YAG – diode pumping, 2

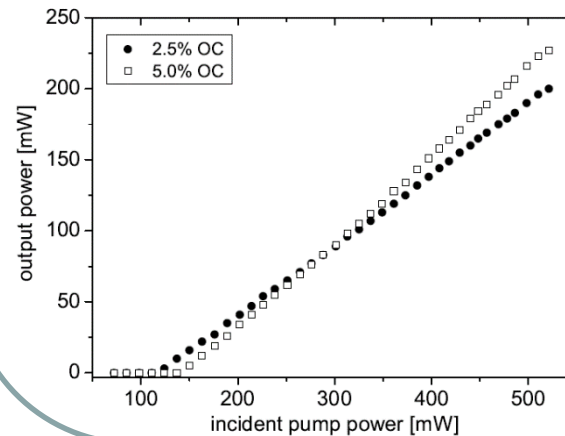
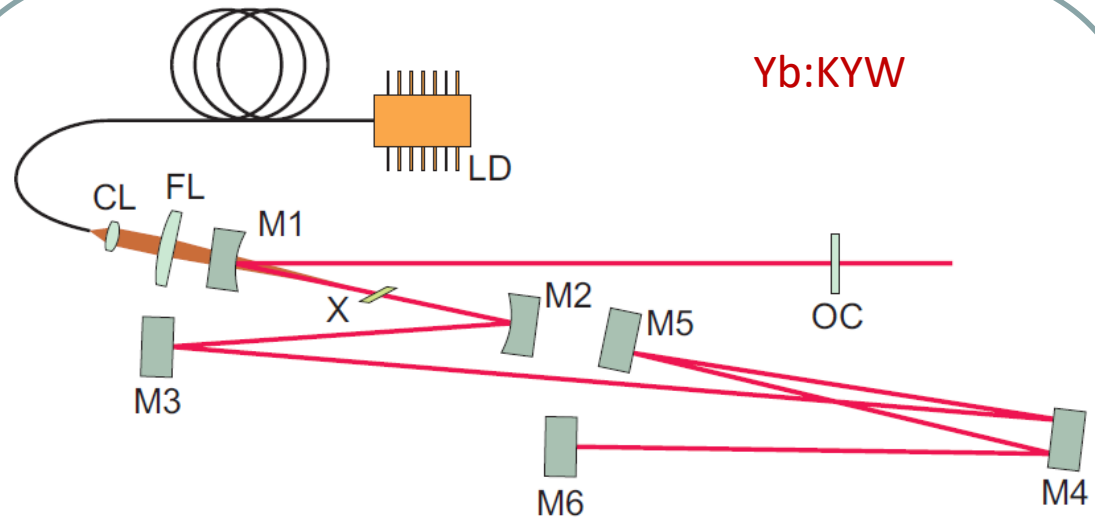
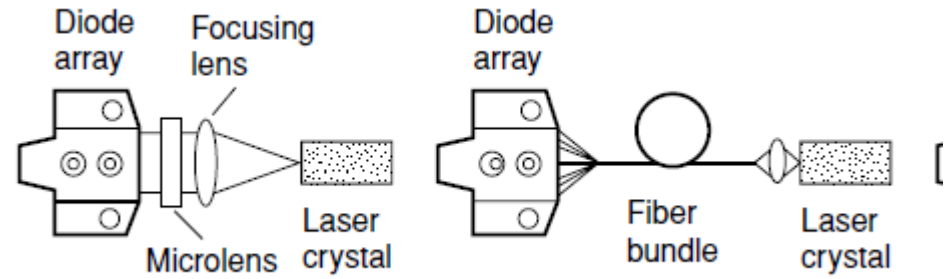
monolithic Nd:YAG laser



T. J. Kane, R. J. Byer, Opt. Lett. **10**, 65 (1985)



longitudinal pumping



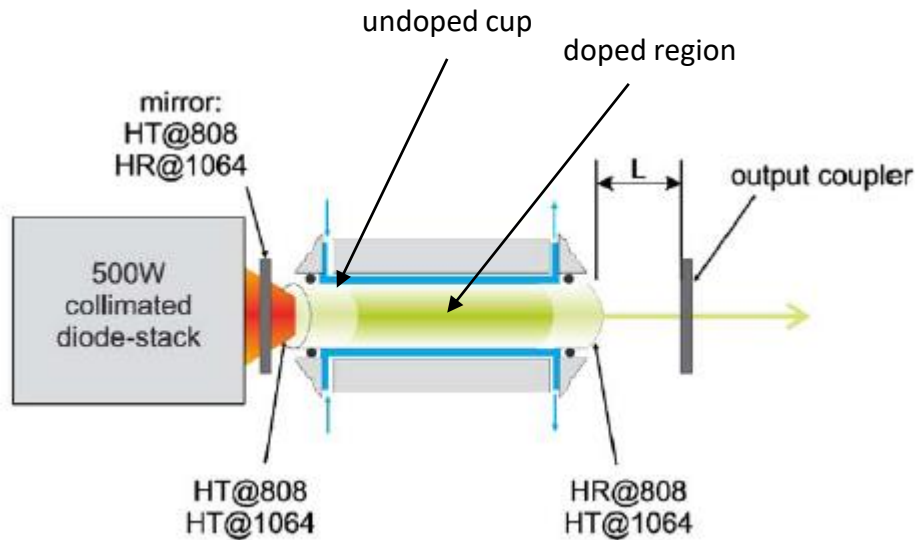
P. Wasylczyk and C. Radzewicz, Laser Physics **19**, 129 (2009)

Nd:YAG – diode pumping, 3

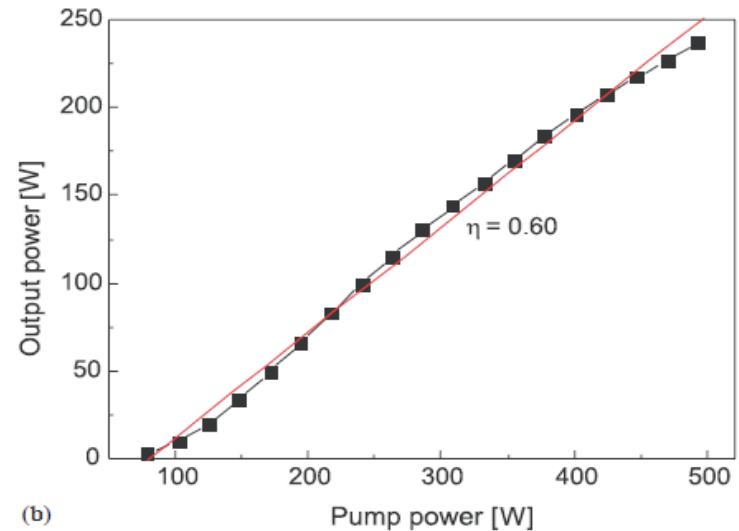
Compact high-power end-pumped Nd:YAG laser

Maik Frede*, Dietmar Kracht, Martin Engelbrecht, Carsten Fallnich

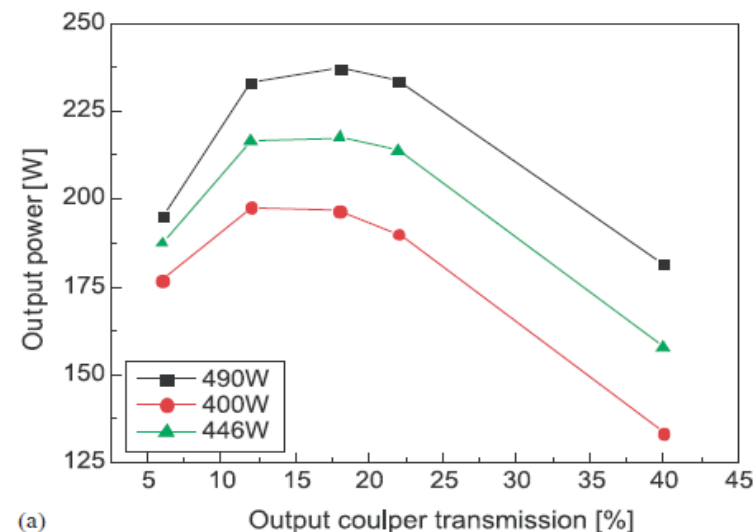
Optics & Laser Technology 38 (2006) 183–185



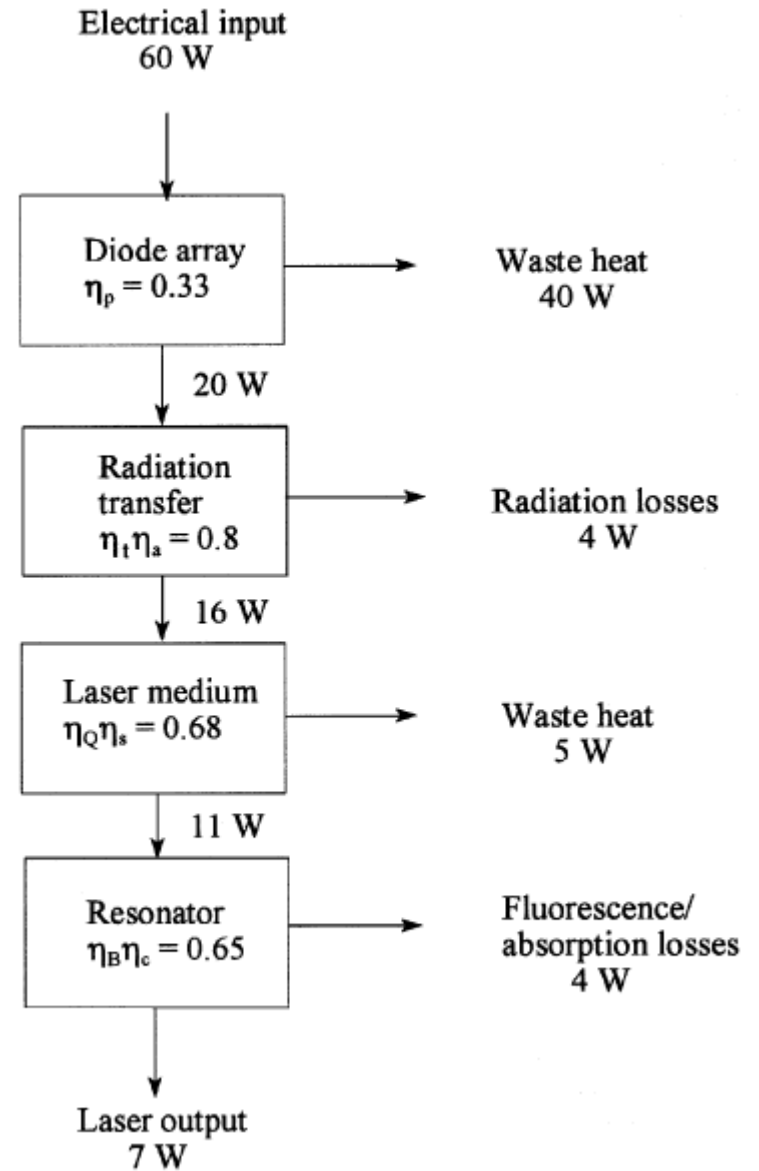
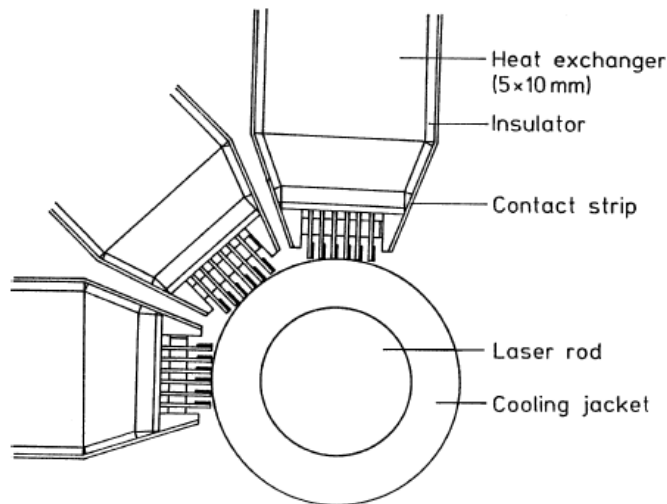
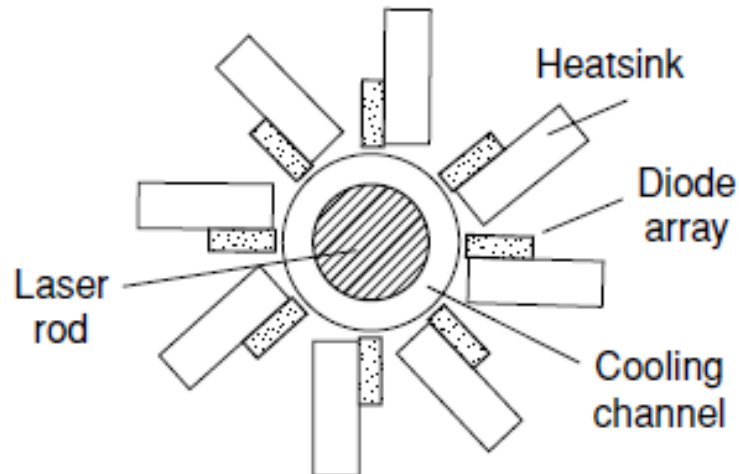
- the cups allow to cool uniformly all the pumped part of the crystal
- diode laser 550W, $3 \times 4 \text{ mm}^2$, $\text{NA}=0.42$
- the rod has a polished cylindrical surface and acts as waveguide for the pump beam
- double-pass of the pump beam – small gain gradient along the crystal axis
- poor quality of the output beam, $M^2=80$



efficiency 48%
slope efficiency 60%



Nd:YAG – diode pumping, 4



commercial Diode-Pumped Solid State Laser (DPSSL)



	Evolution-15	Evolution-30	Evolution-45	Evolution-HE
Wavelength (nm)	527	527	527	527
Pulse Repetition-Rate (kHz)		1 to 10		1 (factory set) ¹
Average Output Power (W)	12 at 1 kHz 15 at 5 kHz 15 at 10 kHz	20 at 1 kHz 30 at 5 kHz 30 at 10 kHz	28 at 1 kHz 45 at 5 kHz 45 at 10 kHz	45 at 1 kHz 75 at 5 kHz 75 at 10 kHz
Energy-Per-Pulse (mJ)	12 at 1 kHz 3 at 5 kHz 1.5 at 10 kHz	20 at 1 kHz 6 at 5 kHz 3 at 10 kHz	28 at 1 kHz 9 at 5 kHz 4.5 at 10 kHz	45 at 1 kHz 15 at 5 kHz 7.5 at 10 kHz
Typical Pulse Width (nsec)(FWHM)	<300 at 1 kHz	<250 at 1 kHz	<250 at 1 kHz	<150 at 1 kHz
Pulse-to-Pulse Energy Stability (% rms)		<1		<1
Polarization Ratio		Horizontal, >100:1		Horizontal, >100:1
Spatial Mode		Multimode		Multimode
Beam Divergence (mrad)(full angle)		<10		<8
Beam Circularity (%)		>80		>80
Nominal Beam Diameter at Output Window (mm)(1/e ²)		3		3

Q-switched lasers

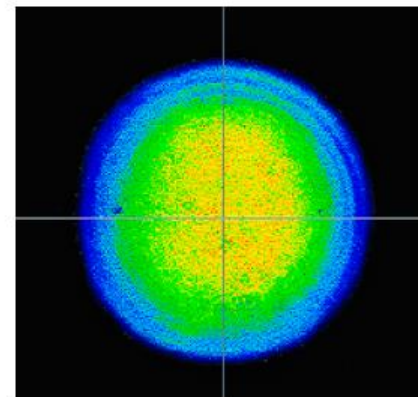
Powerlite DLS 8000 Specifications

Description	8000	8010	8020	8030	8050
Repetition Rate (Hz)	10	10	20	30	50
Energy (mJ)					
1064 nm	1200	1650	1200	650	550
532 ¹ nm	600	800	550	300	210
355 ² nm	310	450	300	150	95
266 nm	120	150	80	50	30
Pulsewidth ³ (nsec)					
1064 nm	6-8	6-8	6-8	7-9	7-9
532 nm	5-7	5-7	5-7	6-8	6-8
355 nm	5-7	5-7	5-7	6-8	6-8
266 nm	5-7	5-7	5-7	6-8	6-8
Linewidth ⁴ (cm ⁻¹)					
Standard	1	1	1	1	1
Injection Seeded, SLM	0.003	0.003	0.003	0.003	0.003
Divergence ⁵ (mrad)	0.45	0.45	0.45	0.5	0.5
Beam Pointing Stability ⁶ (±μrad)	30	30	30	30	30
Beam Diameter	9	9	9	7	7

comercial flashlamp-pumped solid state laser, 2

Powerlite DLS 2 J Specifications

Description	2 J
Repetition Rate (Hz)	10
Energy (mJ)	
1064 nm	3500
532 ¹ nm	2000
Pulsewidth ² (nsec)	
532 nm	4-8
Linewidth ³ (cm ⁻¹)	
Standard	1
Injection Seeded, SLM	0.003
Divergence ⁴ (mrad)	0.45
Beam Pointing Stability ⁵ (±μrad)	30
Beam Diameter (mm)	12
Jitter ⁶ (±ns)	
Unseeded	0.5
Seeded	1.0
Energy Stability ⁷ (±%)	
532 nm	3.0;1.0
Power Drift ⁸ (±%)	
532 nm	6.0
Beam Spatial Profile (Fit to Gaussian) ⁹	
Near Field (<1m)	0.7
Far Field (∞)	0.95
Max Deviation from fitted Gaussian ¹⁰ (±%)	
Near Field (<1m)	40



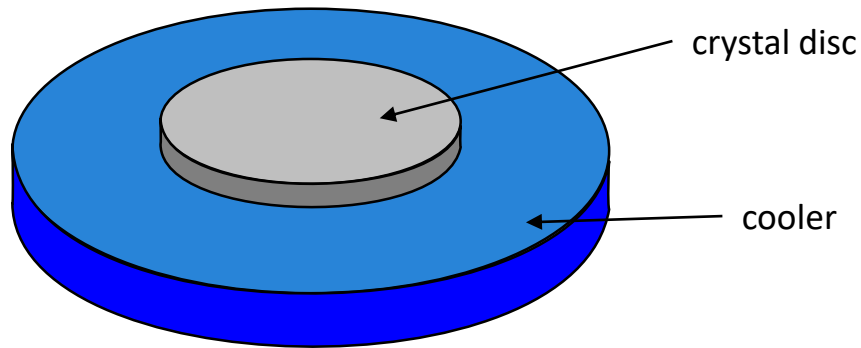
Powerlite DLS 2J Beam Quality -
2 J at 532 nm

heat management in the laser crystal

The limitation for the average power of a solid state laser comes from the heat deposited in the laser crystal. The scaling depends on dimensionality:

Bulk crystal – a cube. Scaling:

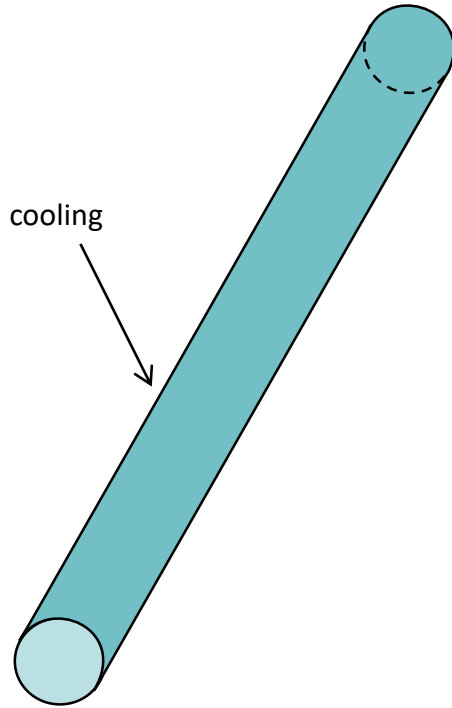
- thermal power $\propto L^3$
- heat removal proportional the crystal surface $\propto L^2$
- cooling efficiency $\propto 1/L$



Flat (2-D) – a disc of constant thickness. Scaling:

- thermal power $\propto L^2$
- heat removal proportional the crystal face surface $\propto L^2$
- cooling efficiency does not depend on the area of the crystal surface

bulk – laser rod



Assume the crystal to be a long cylinder with length $L \gg 2r_0 = \text{diameter}$

The heat is uniformly deposited in the whole volume of the crystal, heat is removed through the cylindrical surface of the crystal which is kept at temperature of the cooling liquid T_0

- thermal power density $Q = \frac{P_{th}}{\pi r_0^2 L}$, with P_{th} being the total power delivered to crystal as heat
- thermal conductivity λ_{th}

Let r be the distance from cylinder axis. Heat diffusion equation

$$\frac{d^2 T}{dr^2} + \frac{1}{r} \frac{dT}{dr} + \frac{Q}{\lambda_{th}} = 0$$

has the solution

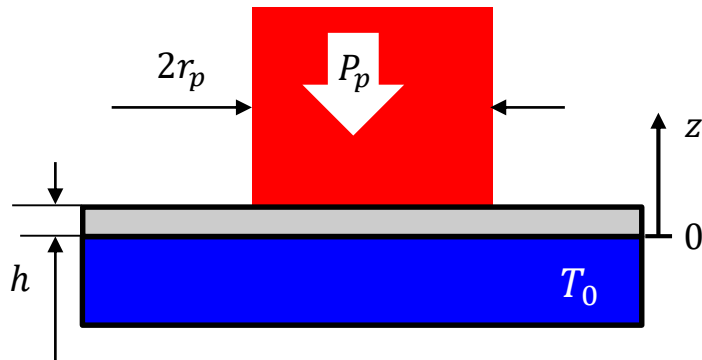
$$T(r) = T_0 + \frac{Q}{4\lambda_{th}} (r_0^2 - r^2)$$

The maximum temperature difference is

$$T(0) - T(r_0) = \frac{Q r_0^2}{4\lambda_{th}} = \frac{P_{th}}{4\pi\lambda_{th}L}$$

The longer the rod the smaller is the temperature gradient. In the limit we have a fiber laser.

disc geometry



P_p - pump power

r_p - radius of the pump beam

η_a - efficiency of the pump absorption

η_h - efficiency of the heat production

I_{th} - thermal power per unit surface

$$I_{th} = \frac{P_{th}}{\pi r_p^2} = \frac{P_p \eta_a \eta_h}{\pi r_p^2}$$

Assume the crystal to be thin – its thickness h is much smaller than r_p . In this case the heat flow is in one direction only – towards the cooler. The corresponding heat diffusion equation gives the temperature distribution along the disc axis

$$T(z) = I_{th} R_{th,d} \left(\frac{z}{h} - \frac{1}{2} \frac{z^2}{h^2} \right)$$

$R_{th,d} = h / \lambda_{th}$ - thermal resistivity of the disc

The maximum temperature difference

$$T(h) - T(0) = \frac{1}{2} I_{th} R_{th,d} = \frac{P_{th} h}{2 \pi r_p^2 \lambda_{th}}$$

$$\frac{P_{th}}{2 \pi \lambda_{th}} \frac{1}{2L} \leftrightarrow \frac{P_{th}}{2 \pi \lambda_{th}} \frac{h}{r_p^2}$$

rod

disc

$$\frac{1}{2L} \leftrightarrow \frac{h}{r_p^2}$$

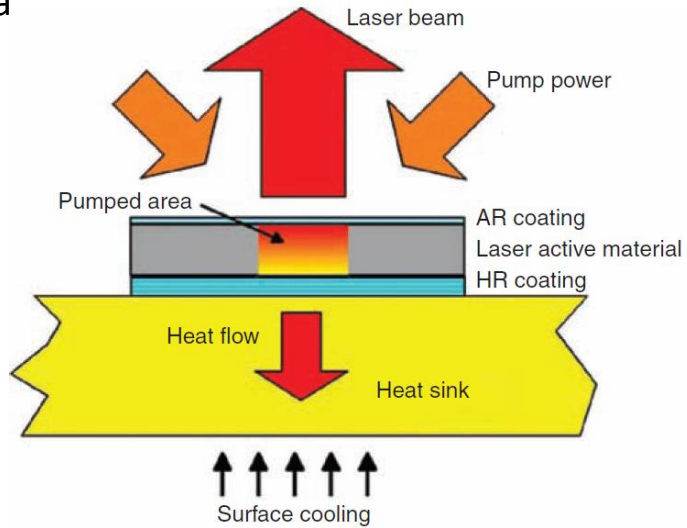
typical numbers:

$$L = 10 \text{ cm}, \quad h = -0.01 \text{ cm}, \quad r_p = 0.5 \text{ cm}$$

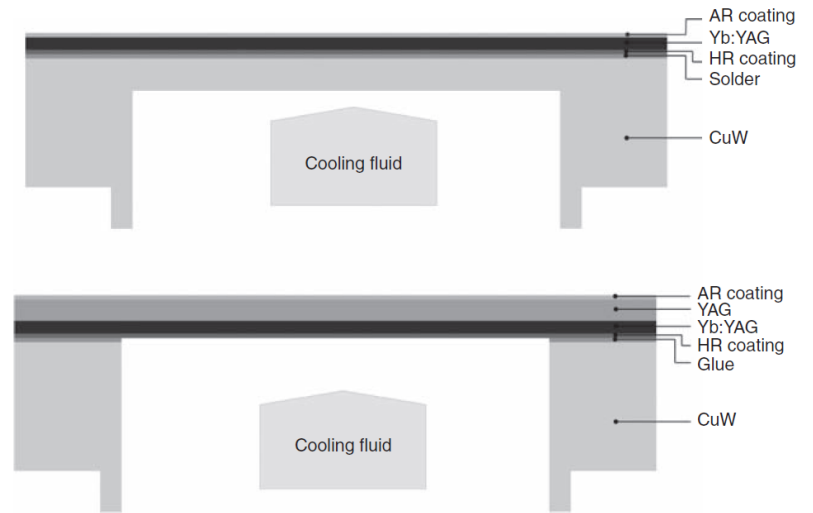
$$\frac{1}{10} \leftrightarrow \frac{1}{25}$$

thin disc solid state lasers

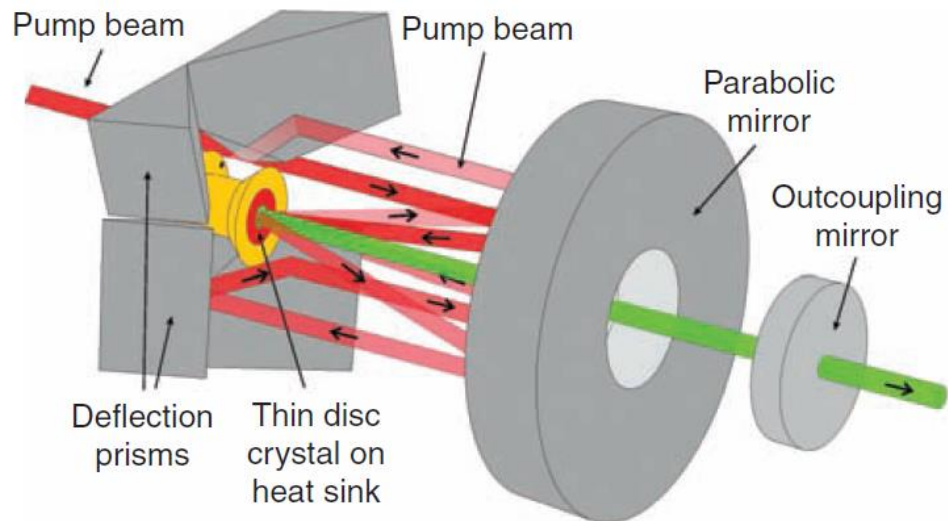
idea



technical realization



multi-pass pump setup



thin disc solid state lasers, 2

materialy

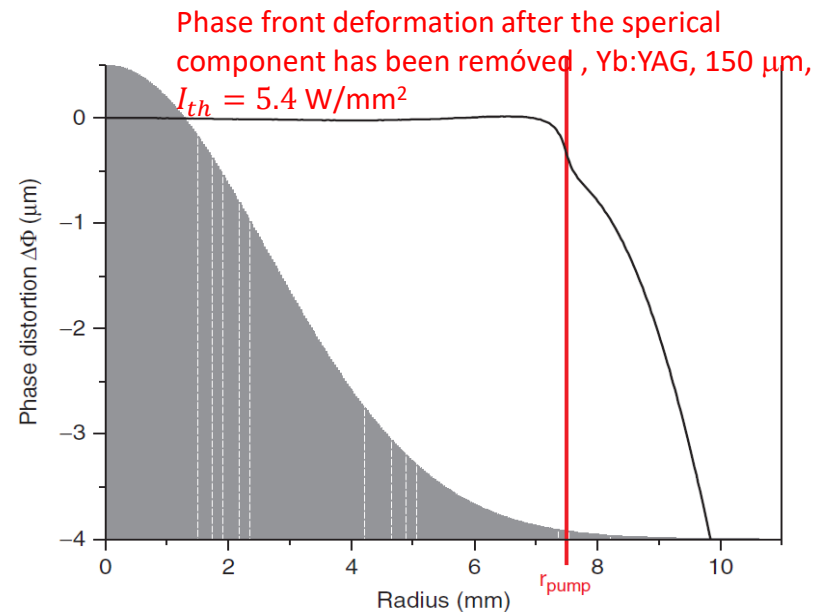
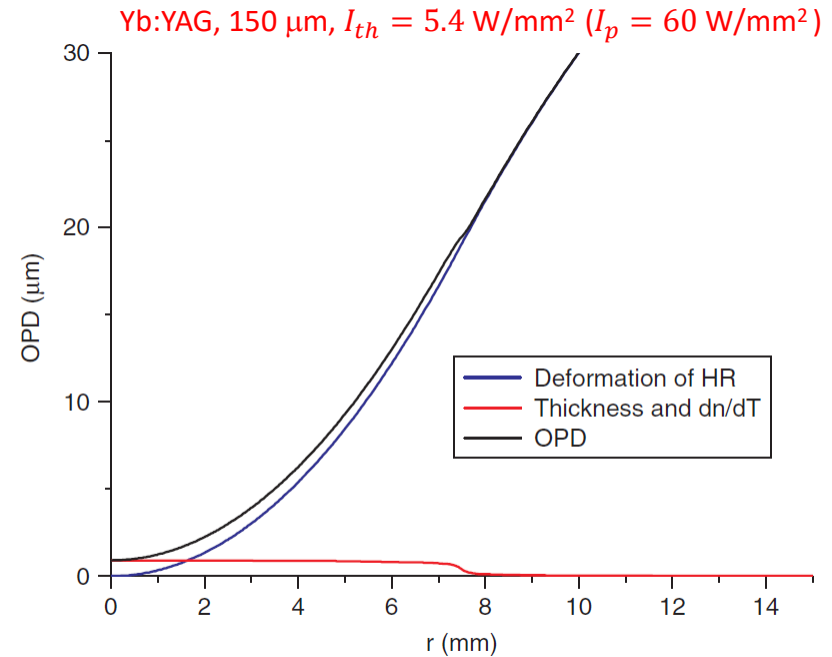
Host Material	
YAG	Yb ³⁺ , Nd ⁽³⁺⁾ 9–11, Tm ⁽³⁺⁾ 12,13, Ho ⁽³⁺⁾ 14
YVO ₄	Yb ⁽³⁺⁾ 15–17, Nd ⁽³⁺⁾ 18–21
Sc ₂ O ₃	Yb ⁽³⁺⁾ 22
Lu ₂ O ₃	Yb ⁽³⁺⁾ 22,23
KY(WO ₄) ₂	Yb ⁽³⁺⁾ 22
KGd(WO ₄) ₂	Yb ⁽³⁺⁾ 22
NaGd(WO ₄) ₂	Yb ⁽³⁺⁾ 15,17
LaSc ₃ (BO ₃) ₄	Yb ⁽³⁺⁾ 24
Ca ₄ YO(BO ₃) ₃	Yb ⁽³⁺⁾ 25
GdVO ₄	Nd ⁽³⁺⁾ 21
ZnSe	Cr ⁽²⁺⁾ 26

Important parameters:

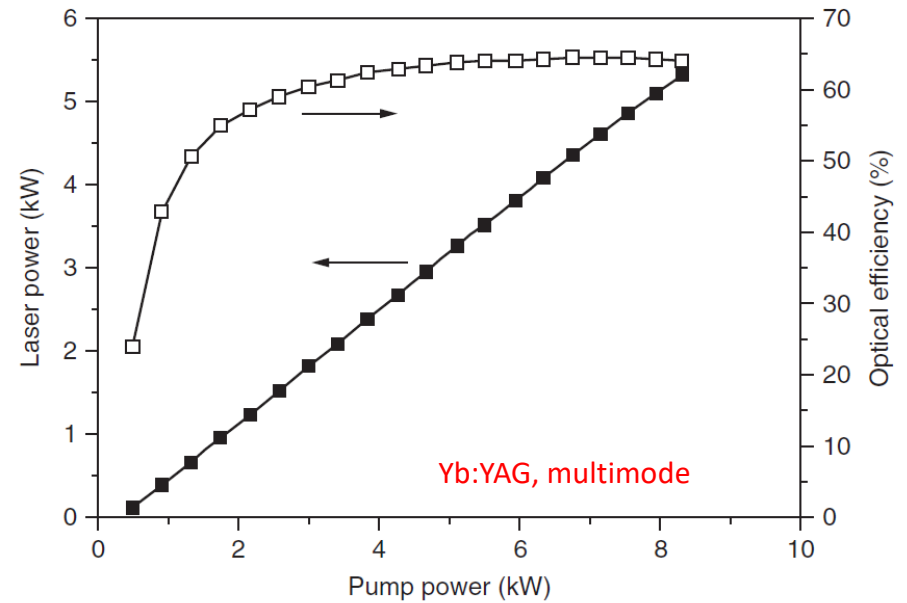
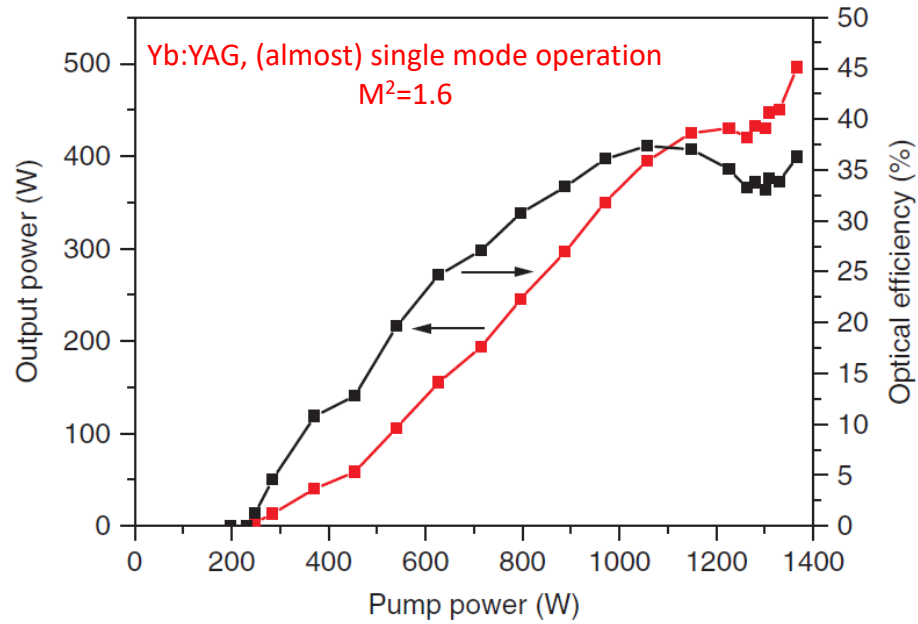
thermal conductivity , $\lambda_{th} = 6 \text{ Wm}^{-1}\text{K}^{-1}$ (for YAG)

absorption coefficient

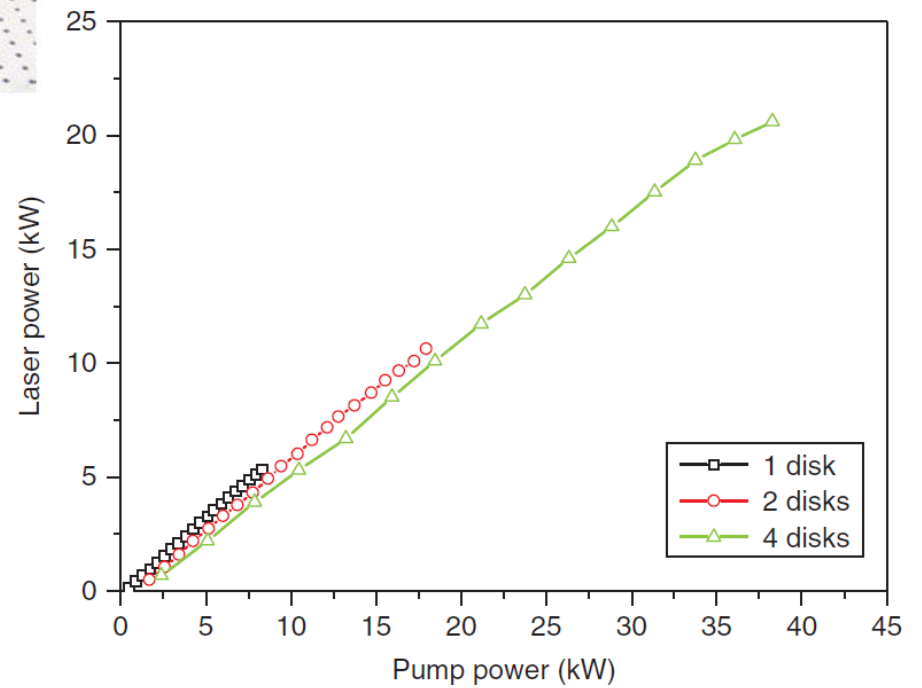
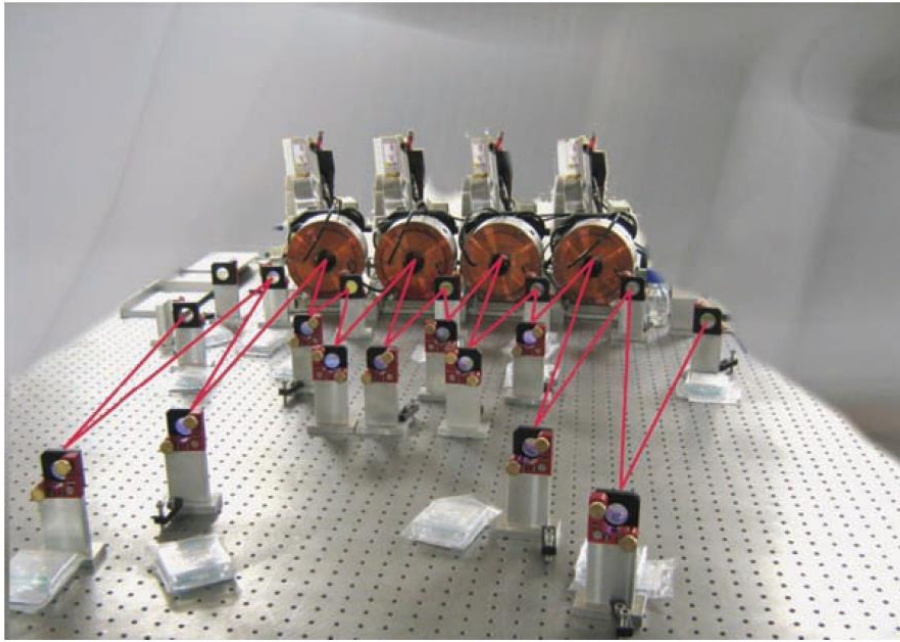
quantum defect: $\eta_{th} = 1 - \lambda_p/\lambda_l = 0.087$ (for Yb:YAG)



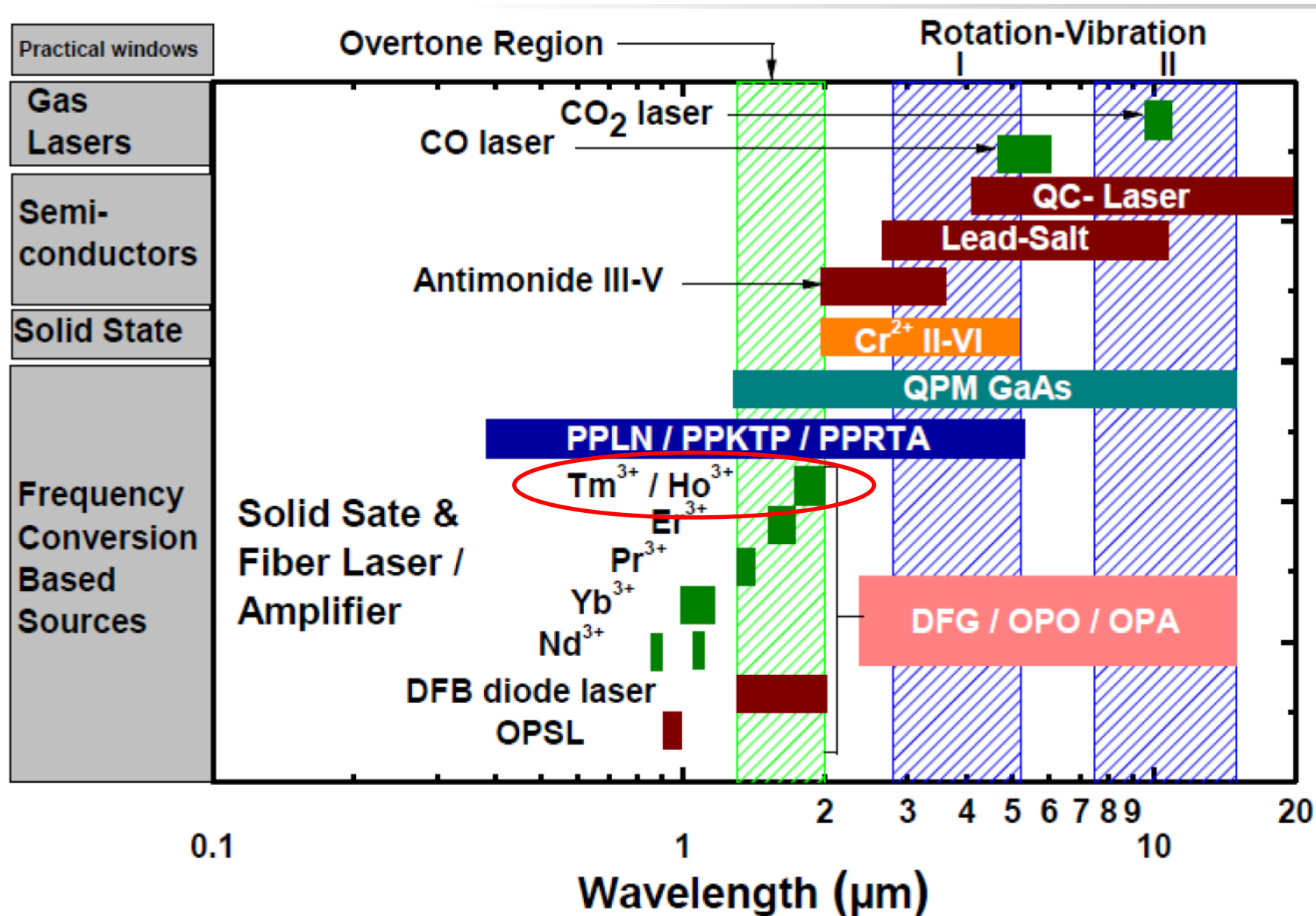
thin disc lasers, some parameters



multi-disc lasers, parameters



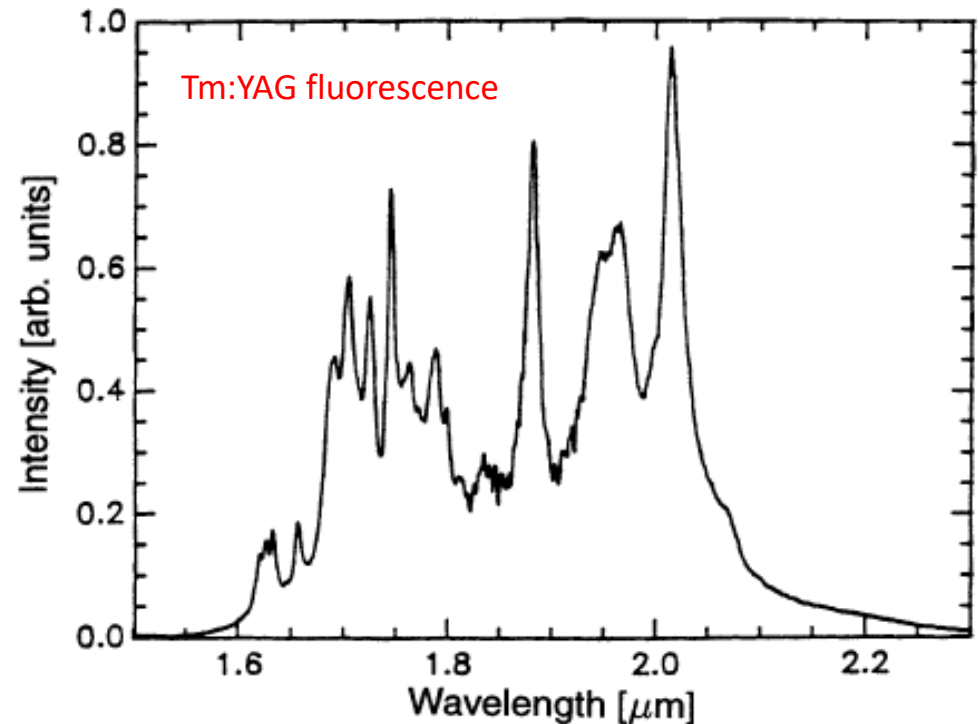
MID IR - eye safe region lasers



MID IR lasers, 2

Tm:YAG

Pump wavelength	780–785 nm
Peak laser wavelength	2.02 μm
Effective cross section at 25°C	$2 \times 10^{-21} \text{ cm}^2$
Fluorescence lifetime	10 ms
Tunability	1.87–2.16 μm



MID IR lasers, 3

Table 11 Important data on Ho^{3+} -doped laser hosts (BYF: BaY_2F_8). Some data are taken from [7, 11, 64, 180, 181]

Host crystal	YAG	YALO	YLF	BYF
Symmetry	cubic	orthorhombic	tetragonal	monoclinic
5I_7 levels [cm^{-1}]	5229, 5232, 5243, 5250, 5303, 5312, 5320, 5341, 5352, 5375, 5395, 5404, 5418, 5455, 5485	5186, 5187, 5222, 5253, 5255, 5264, 5266, 5268, 5280, 5288, 5318, 5326, 5337, 5346, 5357	5153, 5157, 5157, 5164, 5164, 5185, 5185, 5207, 5229, 5229, 5233, 5291, 5293, 5293, 5293	5173, 5177, 5189, 5191, 5197, 5220, 5220, 5220, 5220, 5228, 5256, 5269, 5273, 5276, 5358
$f_{u,(i)}$	0.105 (1), 0.096 (3)	0.100 (0)	0.087 (0)	0.084 (1)
τ_f [ms]	7.8	8.1	16.1	17.9
5I_8 levels [cm^{-1}]	0, 4, 41, 51, 141, 144, 150, 162, 398, 418, 448, 457, 498, 506, 520, 531, 535	0, 6, 37, 48, 58, 71, 100, 126, 137, 193, 211, 222, 289, 327, 425, 474, 499	0, 0, 7, 23, 48, 56, 72, 72, 217, 270, 276, 276, 283, 290, 303, 303, 315	0, 20, 37, 39, 54, 58, 89, 120, 200, 200, 239, 276, 310, 324, 352, 382, 399
$f_{g,(i)}$	0.018 (10), 0.012 (16)	0.012 (15)	0.025 (14)	0.025 (13)
λ_s [nm]	2090, 2121	2122	2062	2060
$\sigma_c(\lambda_s)$ [10^{-20} cm^2]	1.2, 0.55	0.82	1.9 ($E \parallel c$)	1.18 ($E \parallel c$)
$\frac{\sigma_e(\lambda_s)}{\sigma_a(\lambda_s)}$	5.81, 8.13	8.39	3.44	3.42
I_{sat}^s [kW cm^{-2}]	0.866, 1.94	1.26	0.244	0.353
λ_p [nm]	1907, 2017	1976	1948	1933
$\sigma_{a,p}(\lambda_p)$ [10^{-20} cm^2]	1.2, 0.15	0.9	1.2 ($E \parallel c$)	0.7 ($E \parallel c$)
$\frac{\sigma_{e,p}(\lambda_p)}{\sigma_{a,p}(\lambda_p)}$	0.64, 2.53	1.58	0.88	0.74
I_{sat}^p [kW cm^{-2}]	0.949, 0.898 (2090 nm) 2.16, 2.04 (2121 nm)	1.35	0.258	0.376
E_p^{max} [cm^{-1}]	700	550	400	415

MID IR lasers, an example of design

